

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Katsuki HAZAMA

Application No.: To be assigned
(Div. of 09/438,295)

Filed: Concurrently Herewith

Art Unit: 2785

For: MULTILEVEL SEMICONDUCTOR
MEMORY, WRITE/READ METHOD
THERE TO/THEREFROM AND STORAGE
MEDIUM STORING WRITE/READ
PROGRAM

Examiner: Not Yet Assigned

FIRST PRELIMINARY AMENDMENT

MS Non-Fee Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

Prior to examination on the merits, please amend the above-identified U.S. patent application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 4 of this paper.

Remarks/Arguments begin on page 5 of this paper.